

APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

Title of Invention	METHOD OF FABRICATING POLY-CRYSTAL ITO FILM AND POLYCRYSTAL ITO ELECTRODE
Application Type :	regular, utility
Attorney Docket Number :	14150-US-PA
Correspondence address:	
Customer Number:	31561
	
Priority Data:	
Doc.No: 93125996; Country -TW ; Date: 2004-08-30 us-priority-claimed	
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